


	<p>Hersteller-Teilenummer: SI2318CDS-T1-GE3</p>
	<p>Hersteller / Marke: Vishay / Siliconix</p>
	<p>Teil der Beschreibung: MOSFET N-CH 40V 5.6A SOT-23</p>
	<p>Datenblätter:  SI2318CDS-T1-GE3.pdf</p>
	<p>RoHs Status: Bleifrei / RoHS-konform</p>
	<p>Lagerzustand: New original, 81503 pcs Stock Available.</p>
	<p>Liefern von: Hong Kong</p>
<p>Image may be representation. See specs for product details.</p>	<p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>

Spezifikationen

Teilenummer	SI2318CDS-T1-GE3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET N-CH 40V 5.6A SOT-23
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	81503 pcs Stock
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-236-3, SC-59, SOT-23-3
Supplier Device-Gehäuse	SOT-23-3 (TO-236)
Verlustleistung (max)	1.25W (Ta), 2.1W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	40V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	5.6A (Tc)
Rds On (Max) @ Id, Vgs	42 mOhm @ 4.3A, 10V
VGS (th) (Max) @ Id	2.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	9nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	340pF @ 20V
Antriebsspannung (Max Rds On, Min Rds On)	4.5V, 10V
Vgs (Max)	±20V
Verpackung	Tape & Reel (TR)


SI2318CDS-T1-GE3 ist neu im Original, Suche SI2318CDS-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI2318CDS-T1-GE3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI2318CDS-T1-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SI2318CDS Vishay Precision Group SI2318CDS VISHAY</p>	 <p>SI2318DS-T1-GE3 Vishay / Siliconix MOSFET N-CH 40V 3A SOT-23</p>	 <p>SI2318DS-T1-E3 Vishay / Siliconix MOSFET N-CH 40V 3A SOT23-3</p>	 <p>SI2318DS VISHAY/ SI2318DS VISHAY/</p>
 <p>SI2318BDS-T1-E3 VISHAY SI2318BDS-T1-E3 VISHAY</p>	 <p>SI2318CDS-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 40V 5.6A SOT-23</p>	 <p>SI2318DS-T1-E3 Electro-Films (EFI) / Vishay MOSFET N-CH 40V 3A SOT23-3</p>	 <p>SI2318ADS-T1-GE3 V SI2318ADS-T1-GE3 V</p>

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|  SI2315BDS-T1-E3 |  SI2315BDS-T1-E3 |  SI2315BDS-T1-GE3 |  SI2315BDS-T1-GE3 |  SI2315DS |
|  SI2315DS-T1 |  SI2315DS-T1-E3 |  SI2315DS-T1-GE3 |  SI2316-DS |  SI2316BDS-T1-E3 |
|  SI2316BDS-T1-E3 |  SI2316BDS-T1-GE3 |  SI2316BDS-T1-GE3 |  SI2316DS |  SI2316DS-T1-E3 |
|  SI2316DS-T1-E3 |  SI2316DS-T1-GE3 |  SI2316DS-T1-GE3 |  SI2317DS |  SI2317DS-T1-E3 |
|  SI2318ADS-T1-GE3 |  SI2318BDS-T1-E3 |  SI2318BDS-T1-GE3 |  SI2318CDS-T1-E3 |  SI2318CDS-T1-GE3 |
|  SI2318DS |  SI2318DS-T1-E3 |  SI2318DS-T1-E3 |  SI2318DS-T1-GE3 |  SI2318DS-T1-GE3 |
|  SI2319ADS-T1-GE3 |  SI2319C95TF |  SI2319CDS-T1-E3 |  SI2319CDS-T1-GE3 |  SI2319CDS-T1-GE3 |
|  SI2319DDS-T1-GE3 |  SI2319DS |  SI2319DS-T1-E3 |  SI2319DS-T1-E3 |  SI2319DS-T1-GE3 |
|  SI2319DS-T1-GE3 |  SI2320DS |  SI2320DS-T1-E3 |  SI2320DS-T1-GE3 |  SI2321DS-T1-E3 |
|  SI2321DS-T1-E3 |  SI2321DS-T1-GE3 |  SI2321DS-T1-GE3 |  SI2323CDS-T1 |  SI2323CDS-T1-E3 |

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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